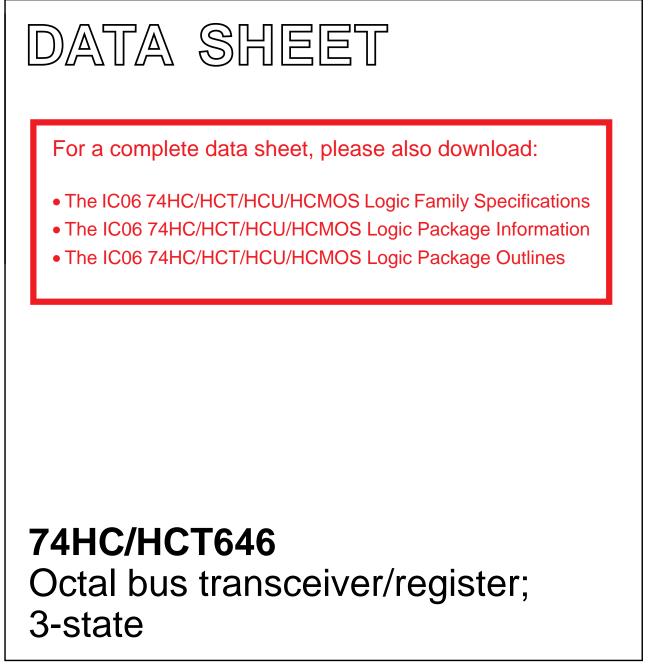
INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC06 September 1993



74HC/HCT646

FEATURES

- Independent register for A and B buses
- Multiplexed real-time and stored data
- Output capability: bus driver
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT646 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT646 consist of bus transceiver circuits with 3-state outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the internal registers. Data on the "A" or "B" bus will be

clocked into the registers as the appropriate clock $(CP_{AB} \text{ and } CP_{BA})$ goes to a HIGH logic level. Output enable (\overline{OE}) and direction (DIR) inputs are provided to control the transceiver function. In the transceiver mode, data present at the high-impedance port may be stored in either the "A" or "B" register, or in both. The select source inputs (S_{AB} and S_{BA}) can multiplex stored and real-time (transparent mode) data. The direction (DIR) input determines which bus will receive data when \overline{OE} is active (LOW). In the isolation mode ($\overline{OE} = HIGH$), "A" data may be stored in the "B" register and/or "B" data may be stored in the "A" register.

When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two buses, A or B, may be driven at a time.

The "646" is functionally identical to the "648", but has non-inverting data paths.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25 \ ^{\circ}C$; $t_r = t_f = 6 \ ns$

SYMBOL	PARAMETER	CONDITIONS	ТҮР	UNIT	
STWIDUL		CONDITIONS	НС	нст	
t _{PHL} / t _{PLH}	propagation delay A_n , B_n to B_n , A_n	C _L = 15 pF; V _{CC} = 5 V	11	13	ns
f _{max}	maximum clock frequency		69	85	MHz
CI	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per channel	notes 1 and 2	30	33	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz

 $f_o = output frequency in MHz$

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs}$

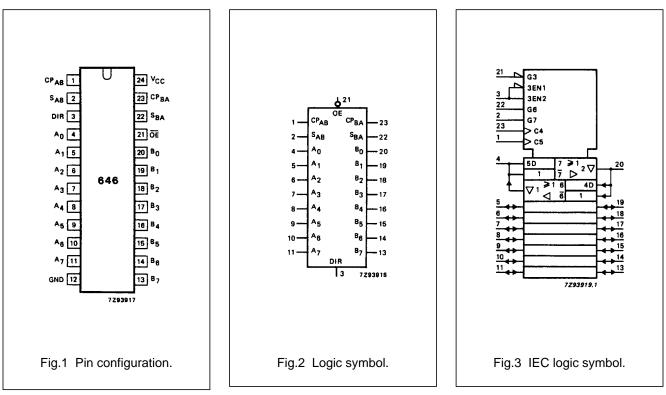
- C_L = output load capacitance in pF
- V_{CC} = supply voltage in V
- 2. For HC the condition is $V_I = GND$ to V_{CC} For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5$ V

ORDERING INFORMATION

See "74HC/HCT/HCU/HCMOS Logic Package Information".

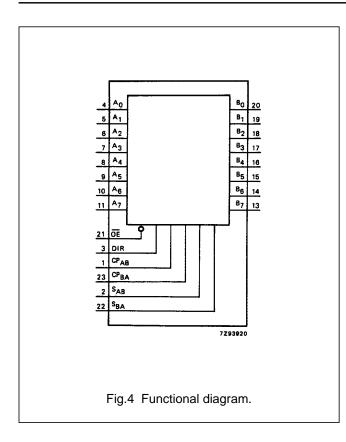
PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	CP _{AB}	A to B clock input (LOW-to-HIGH, edge-triggered)
2	S _{AB}	select A to B source input
3	DIR	direction control input
4, 5, 6, 7, 8, 9, 10, 11	A ₀ to A ₇	A data inputs/outputs
12	GND	ground (0 V)
20, 19, 18, 17, 16, 15, 14, 13	B ₀ to B ₇	B data inputs/outputs
21	ŌĒ	output enable input (active LOW)
22	S _{BA}	select B to A source input
23	CP _{BA}	B to A clock input (LOW-to-HIGH, edge-triggered)
24	V _{CC}	positive supply voltage



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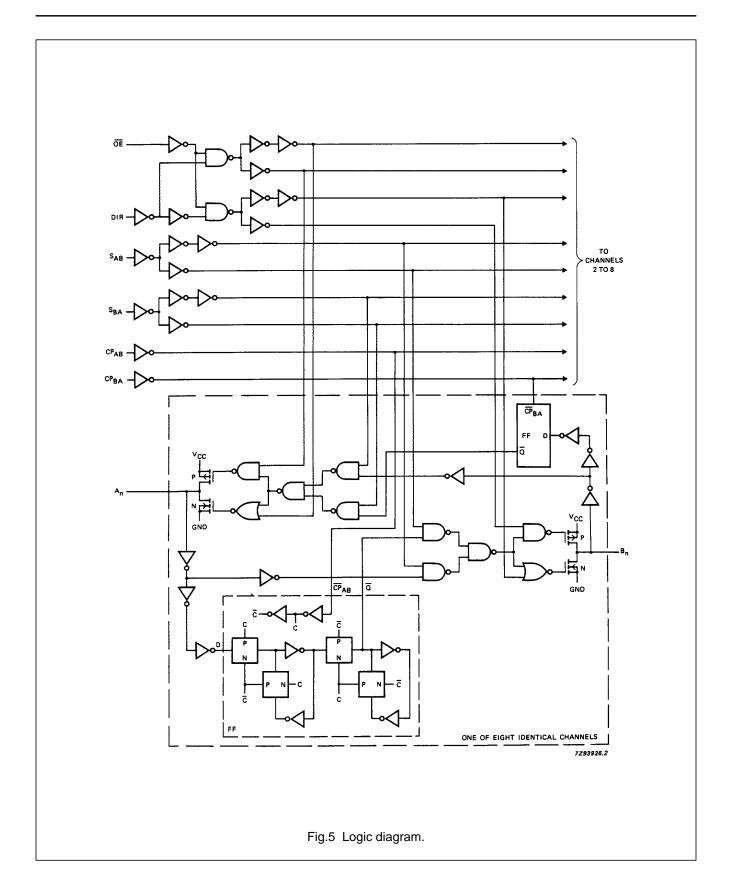
FUNCTION TABLE

		INPL	JTS ⁽¹⁾			DATA	I/O ⁽²⁾	FUNCTION			
ŌE	DIR	CP _{AB}	CPBA	S _{AB}	S _{BA}	A ₀ to A ₇	B ₀ to B ₇				
H H	X X	H or L ↑	H or L ↑	X X	X X	input	input	isolation store A and B data			
L L	L L	X X	X H or L	X X	L H	output	input	real-time B data to A bus stored B data to A bus			
L L	H H	X H or L	X X	L H	X X	input	output	real-time A data to B bus stored A data to B bus			

Notes

- 1. H = HIGH voltage level
 - L = LOW voltage level
 - X = don't care
 - \uparrow = LOW-to-HIGH level transition
- The data output functions may be enabled or disabled by various signals at the OE and DIR inputs. Data input functions are always enabled, i.e., data at the bus inputs will be stored on every LOW-to-HIGH transition on the clock inputs.

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DC CHARACTERISTICS FOR 74HC

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications". Output capability: bus driver I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

				-	T _{amb} (°	C)				TEST CONDITIONS	
CVMDO!			74HC								
SYMBOL	PARAMETER		+25			-40 to +85		-40 to +125		V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		(.,	
t _{PHL} / t _{PLH}	propagation delay A _n ,B _n to B _n ,A _n		39 14 11	135 27 23		170 34 29		205 41 35	ns	2.0 4.5 6.0	Fig.6
t _{PHL} / t _{PLH}	propagation delay CP_{AB}, CP_{BA} to B_n, A_n		66 24 19	220 44 37		275 55 47		330 66 56	ns	2.0 4.5 6.0	Fig.7
t _{PHL} / t _{PLH}	propagation delay S _{AB} ,S _{BA} to B _n ,A _n		55 20 16	190 38 32		240 48 41		285 57 48	ns	2.0 4.5 6.0	Fig.8
t _{PZH} / t _{PZL}	3-state output enable time OE to A _n ,B _n		47 17 14	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig.9
t _{PHZ} / t _{PLZ}	$\begin{array}{llllllllllllllllllllllllllllllllllll$		58 21 17	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig.9
t _{PZH} / t _{PZL}	3-state output enable time DIR to A _n ,B _n		50 18 14	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig.10
t _{PHZ} / t _{PLZ}	3-state output disable time DIR to A _n ,B _n		50 18 14	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig.10
t _{THL} / t _{TLH}	output transition time		14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig.6 and Fig.8
t _W	clock pulse width HIGH or LOW CP _{AB} or CP _{BA}	80 16 14	25 9 7		100 24 20		120 24 20		ns	2.0 4.5 6.0	Fig.7
t _{su}	set-up time A_n, B_n to CP_{AB}, CP_{BA}	60 12 10	-3 -1 -1		75 15 13		90 18 15		ns	2.0 4.5 6.0	Fig.7
t _h	hold time A_n, B_n to CP_{AB}, CP_{BA}	35 7 6	6 2 2		45 9 8		55 11 9		ns	2.0 4.5 6.0	Fig.7
f _{max}	maximum clock pulse frequency	6.0 30 35	21 63 75		4.8 24 28		4.0 20 24		MHz	2.0 4.5 6.0	Fig.7

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DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications".

Output capability: bus driver I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
S _{AB} , S _{BA}	0.60
A_0 to A_7 and B_0 to B_7	0.75

INPUT	UNIT LOAD COEFFICIENT
CP _{AB} , CP _{BA}	1.50
OE	1.50
DIR	1.25

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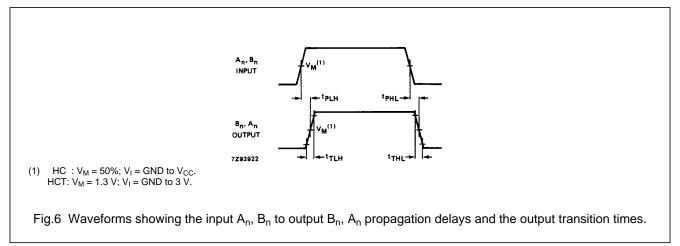
AC CHARACTERISTICS FOR 74HCT

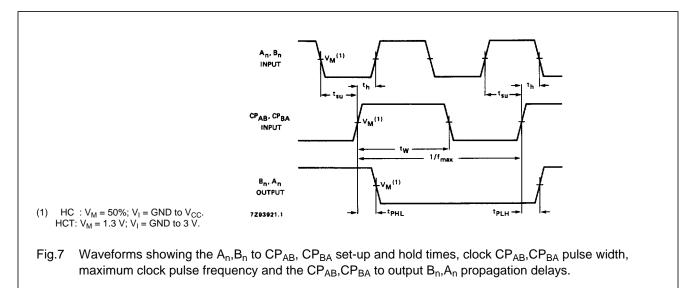
 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

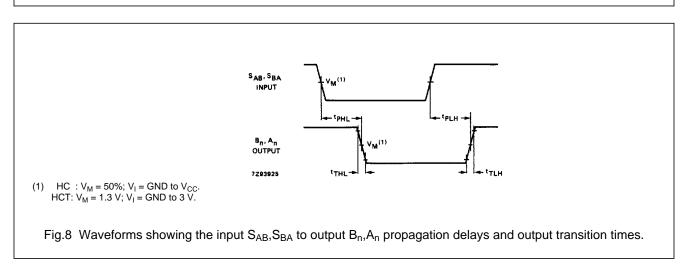
		Т _{ать} (°С) 74НСТ								TES	T CONDITIONS
SYMBOL	PARAMETER										
STWIDUL	FARAINETER	+25			-40 to +85		-40 to +125		UNIT	V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.	1		
t _{PHL} / t _{PLH}	propagation delay A _n ,B _n to B _n ,A _n		16	30		38		45	ns	4.5	Fig.6
t _{PHL} / t _{PLH}	propagation delay CP _{AB} ,CP _{BA} to B _n ,A _n		23	44		55		66	ns	4.5	Fig.7
t _{PHL} / t _{PLH}	propagation delay S _{AB} ,S _{BA} to B _n ,A _n		26	46		58		69	ns	4.5	Fig.8
t _{PZH} / t _{PZL}	$\begin{array}{c} 3\text{-state output enable time} \\ \overline{\text{OE}} \text{ to } A_n, B_n \end{array}$		21	40		50		60	ns	4.5	Fig.9
t _{PHZ} / t _{PLZ}			20	35		44		53	ns	4.5	Fig.9
t _{PZH} / t _{PZL}	3-state output enable time DIR to A _n ,B _n		21	40		50		60	ns	4.5	Fig.10
t _{PHZ} / t _{PLZ}	3-state output disable time DIR to A _n ,B _n		21	35		44		53	ns	4.5	Fig.10
t _{THL} / t _{TLH}	output transition time		5	12		15		18	ns	4.5	Fig.6 and Fig.8
t _W	clock pulse width HIGH or LOW CP _{AB} or CP _{BA}	16	8		20		24		ns	4.5	Fig.7
t _{su}	set-up time A _n ,B _n to CP _{AB} ,CP _{BA}	12	3		15		18		ns	4.5	Fig.7
t _h	hold time A_n, B_n to CP_{AB}, CP_{BA}	5	1		5		5		ns	4.5	Fig.7
f _{max}	maximum clock pulse frequency	30	77		24		20		MHz	4.5	Fig.7

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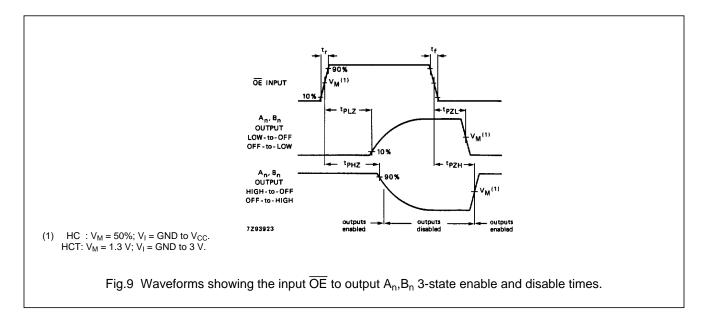
AC WAVEFORMS

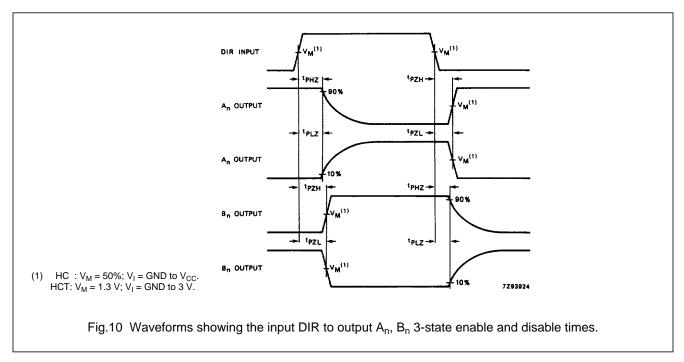






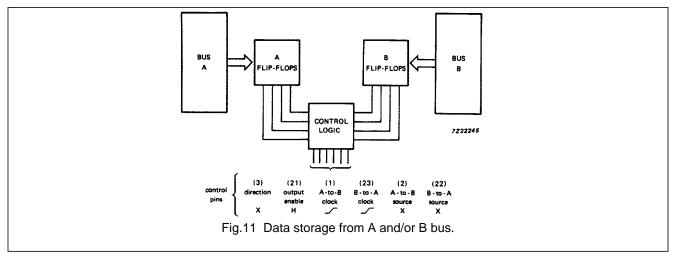
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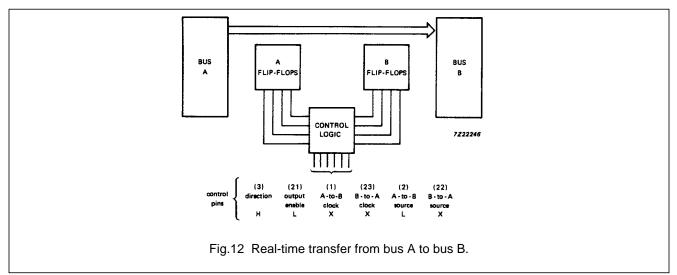


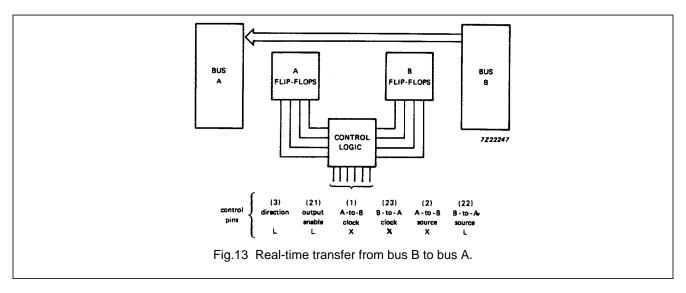


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APPLICATION INFORMATION







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PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".